# NSN 5962-01-152-0905

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View Online at https://aerobasegroup.com/nsn/5962-01-152-0905

# **Body Length:**

Between 1.236 inches and 1.290 inches

# Body Width:

0.560 inches

# **Body Height:**

Between 0.130 inches and 0.170 inches

# **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

# **Features Provided:**

Hermetically sealed and burn in and programmed and 3-state output and bipolar

# Inclosure Material:

Ceramic

### Inclosure Configuration:

Dual-in-line

# **Output Logic Form:**

Transistor-transistor logic

### Input Circuit Pattern:

11 input

# **Current Rating Per Characteristic:**

185.00 milliamperes reverse current, dc absolute

# **Terminal Surface Treatment:**

Solder

# Voltage Rating And Type Per Characteristic:

7.0 volts power source

# **Capitance Rating Per Characteristic:**

5.00 input picofarads and 8.00 output picofarads

# Time Rating Per Chacteristic:

90.00 nanoseconds access

#### Memory Device Type:

Prom

# Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

#### **Terminal Type And Quantity:**

24 printed circuit

## Shelf Life:

N/a

## Unit Of Measure:

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# Demilitarization:

Yes - demil/mli

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